

# ZMU100 - ZMU180

$V_Z$  : 100 to 180V  
 $P_D$  : 1W

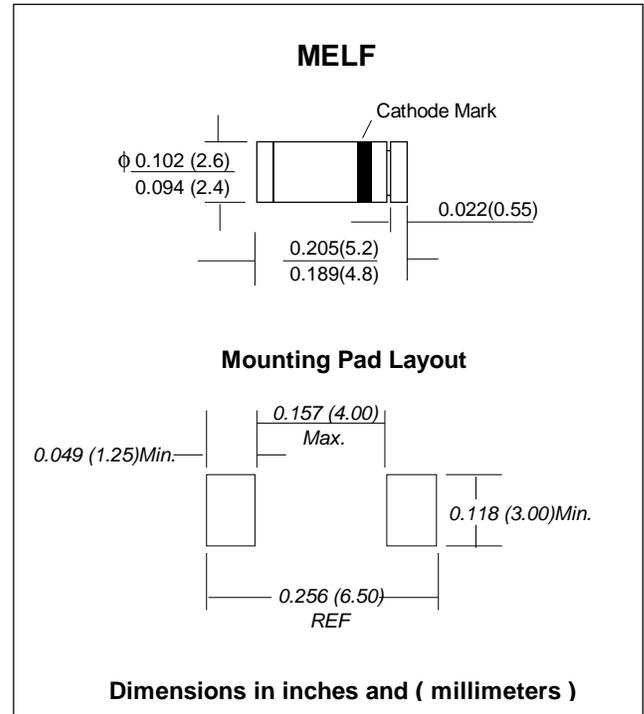
## FEATURES :

- \* Silicon planar power zener diodes
- \* For use in stabilizing and clipping circuits with higher power rating.
- \* The zener voltages are graded according to the tolerances are available upon request.
- \* These diodes are also available in the DO-41 case with the type designation ZPU100 ... ZPU180.
- \* **Pb / RoHS Free**

## MECHANICAL DATA :

- \* Case : MELF Glass Case
- \* Weight : 0.25 g

## ZENER DIODES



## Maximum Ratings and Thermal Characteristics (Rating at 25 °C ambient temperature unless otherwise specified.)

Parameter	Symbol	Value	Unit
Zener Current see Table "Characteristics"			
Power Dissipation	$P_D$	1 <sup>(1)</sup>	W
Thermal Resistance Junction to Ambient Air	$R_{\theta JA}$	170 <sup>(1)</sup>	°C/W
Junction temperature	$T_J$	-65 to + 150	°C
Storage temperature range	$T_S$	-65 to + 150	°C

Notes: (1) Valid provided that electrodes are kept at ambient temperature

## Electrical Characteristics (Ratings at 25°C ambient temperature unless otherwise specified.)

Type	Zener Voltage $V_Z$ @ $I_{ZT}$		Test Current $I_{ZT}$	Maximum Zener Impedance $f = 1\text{kHz}$ $Z_{ZT} @ I_{ZT}$	Reverse Voltage at $I_R = 0.5\text{mA}$ $V_R$	Admissible Zener current <sup>(2)</sup> $I_Z$	Temp. Coeff. Of Zener Voltage at $I_{ZT}$ $a_{VZ} (10^{-4}/^\circ\text{C})$	
	Min (V)	Max (V)					Min	Max
ZMU100	88	110	5	140 (<300)	>75	7	9	13
ZMU120	107	134	5	170 (<330)	>90	6	9	13
ZMU130	130	165	5	200 (<360)	>112	5	9	13
ZMU180	160	200	5	220 (<380)	>134	4	9	13

Notes:

(1) Tested with pulses  $t_p = 5\text{ms}$

(2) Valid provided that electrodes are kept at ambient temperature